

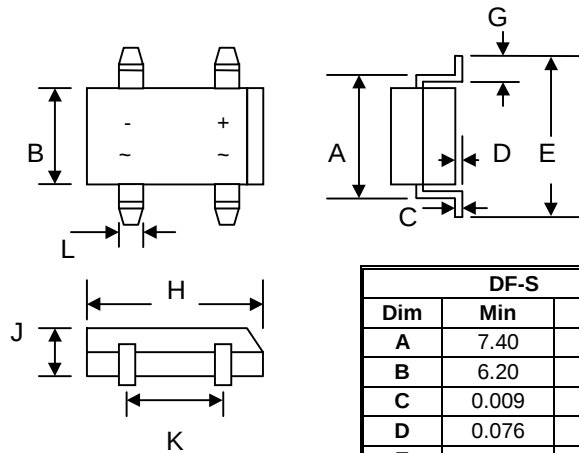


DF005S – DF10S

1.0A SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Surge Current Capability
- Designed for Surface Mount Application
- Plastic Material – UL Recognition Flammability Classification 94V-O



Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Case
- Weight: 0.38 grams (approx.)
- Mounting Position: Any
- Marking: Type Number

*Low profile models (J = 2.20~2.50mm) are available.
Please consult factory.

DF-S		
Dim	Min	Max
A	7.40	7.90
B	6.20	6.50
C	0.009	0.25
D	0.076	0.33
E	—	10.40
G	1.02	1.53
H	8.13	8.51
J*	3.20	3.40
K	5.0	5.20
L	1.00	1.20
All Dimensions in mm		

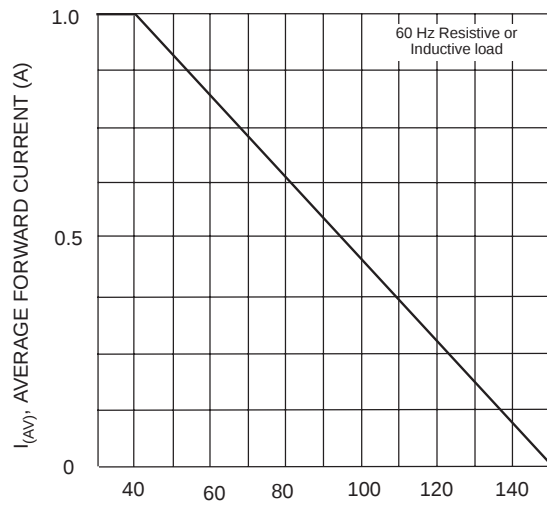
Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

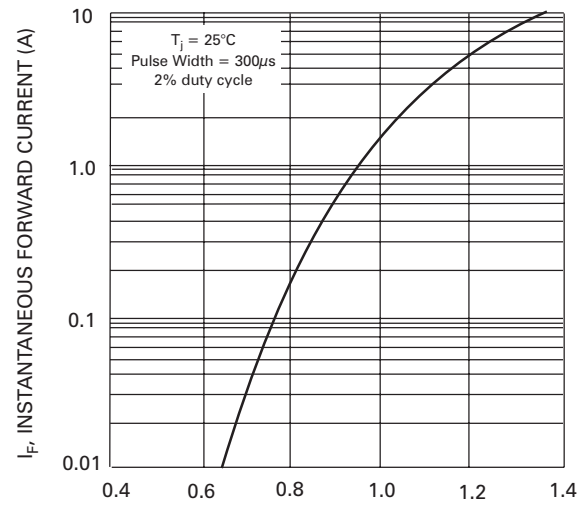
Characteristic	Symbol	DF 005S	DF 01S	DF 02S	DF 04S	DF 06S	DF 08S	DF 10S	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current @T _A = 40°C	I _O	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30							A
Forward Voltage per element @I _F = 1.0A	V _{FM}	1.1							V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 125°C	I _{RM}	10 500							μA
Typical Junction Capacitance per element (Note 1)	C _j	25							pF
Typical Thermal Resistance (Note 2)	R _{θJA}	110							K/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150							°C

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

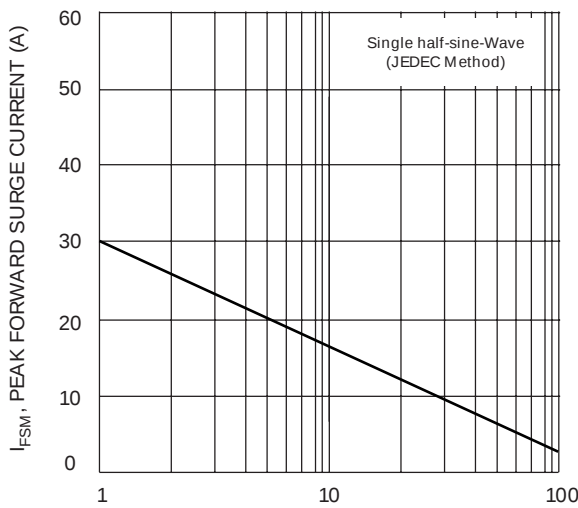
2. Thermal resistance junction to ambient mounted on PC board with 5.0mm² (0.03mm thick) land areas.



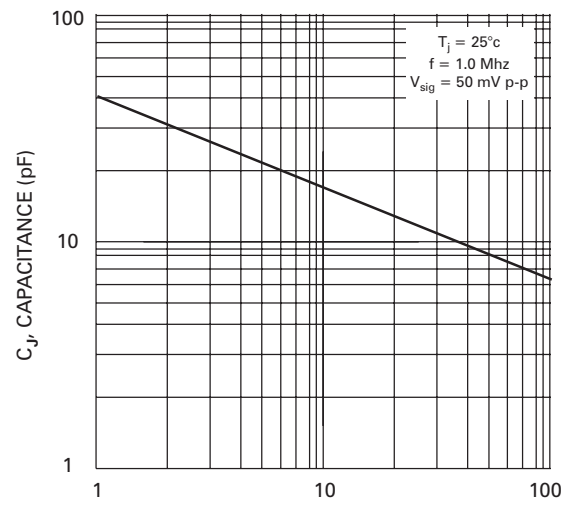
T_A , AMBIENT TEMPERATURE ($^{\circ}\text{C}$)
Fig. 1 Output Current Derating Curve



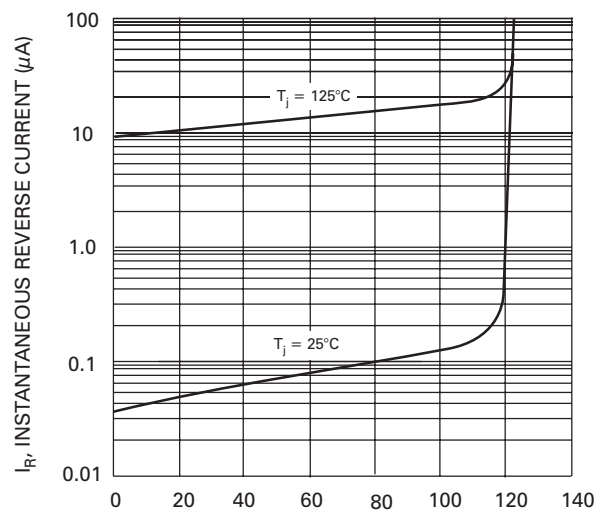
V_F , INSTANTANEOUS FORWARD VOLTAGE (V)
Fig. 2 Typ Forward Characteristics (per element)



NUMBER OF CYCLES AT 60 Hz
Fig. 3 Max Non-Repetitive Peak Forward Surge Current



V_R , REVERSE VOLTAGE (V)
Fig. 4 Typ Junction Capacitance (per element)



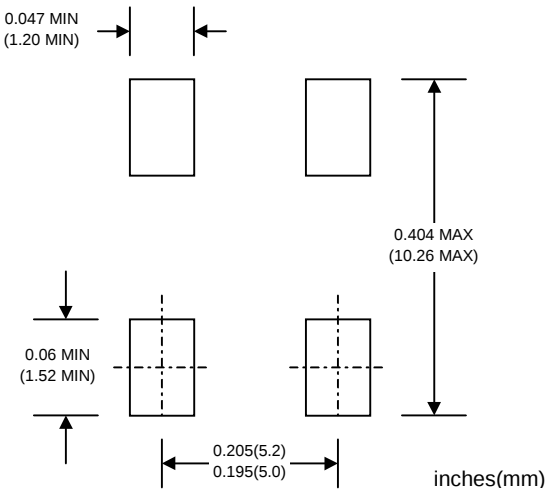
PERCENT OF RATED PEAK REVERSE VOLTAGE (%)
Fig. 5 Typ Reverse Characteristics (per element)

ORDERING INFORMATION

Product No.◆	Package Type	Shipping Quantity
DF005S-T3	DIL Bridge SMD	1500/Tape & Reel
DF005S	DIL Bridge SMD	50 Units/Tube
DF01S-T3	DIL Bridge SMD	1500/Tape & Reel
DF01S	DIL Bridge SMD	50 Units/Tube
DF02S-T3	DIL Bridge SMD	1500/Tape & Reel
DF02S	DIL Bridge SMD	50 Units/Tube
DF04S-T3	DIL Bridge SMD	1500/Tape & Reel
DF04S	DIL Bridge SMD	50 Units/Tube
DF06S-T3	DIL Bridge SMD	1500/Tape & Reel
DF06S	DIL Bridge SMD	50 Units/Tube
DF08S-T3	DIL Bridge SMD	1500/Tape & Reel
DF08S	DIL Bridge SMD	50 Units/Tube
DF10S-T3	DIL Bridge SMD	1500/Tape & Reel
DF10S	DIL Bridge SMD	50 Units/Tube

Products listed in **bold** are WTE **Preferred** devices.
◆T3 suffix refers to a 13" reel.
Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.

RECOMMENDED FOOTPRINT



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